Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-195-3855

| Inclosure Material: |
|---|
| Metal |
| Overall Length: |
| 0.195 inches |
| Terminal Length: |
| 1.500 inches |
| Overall Diameter: |
| 0.550 inches |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| To-8 |
| Response Time: |
| 25.0 nanoseconds |
| Mounting Method: |
| Terminal |
| Terminal Circle Diameter: |
| 0.020 inches |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 50.0 breakdown voltage, dc |
| Maximum Operating Tempurature Per Measurement Point: |
| 125.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A110a0 |
| |
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